Electronic transport in chemical vapor deposited graphene synthesized on Cu: Quantum Hall effect and weak localization


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Erratum “Electronic transport in chemical vapor deposited graphene synthesized on Cu: Quantum Hall effect and weak localization” [Appl. Phys. Lett. 96, 122106 (2010)]

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This erratum is for correcting the affiliations of authors Qingkai Yu, W. Wu, Z. Liu, J. Bao, and S. S. Pei. Corrected affiliations are listed above.

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